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EXPEDITED PROCEDURE
UNDER 37 C.F.R. §1.116

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Makoto SASAKI

Serial No.: 09/532,892

Group Art Unit: 2815

Filed: March 22, 2000

Examiner: P. Brock, II

For: SEMICONDUCTOR DEVICE WITH COPPER FUSE SECTION

Honorable Commissioner of Patents
Washington, D.C. 20231

AMENDMENT UNDER 37 C.F.R. §1.116

Sir:

In response to the Office Action dated September 30, 2002, please amend the above-identified application as follows:

IN THE CLAIMS:

Please cancel claims 17-19 and 26-28 without prejudice or disclaimer.

Please amend claims 1 and 20 as follows:

- D'
1. (Four Times Amended) A semiconductor memory device, including a copper fuse section that is oxidized by a laser beam in an oxidizing environment, comprising:
 - a dielectric film including a first film section formed on a substrate, a second film section formed on said first film section, and a third film section formed over said second film section;
 - a wiring line structure, including:
 - a first and a second wiring line, each of said first and second wiring lines formed directly upon said second film section of said dielectric film without an intervening film